

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	("6255146").PN.	US-PGPUB; USPAT	OR	OFF	2006/04/05 10:25
L2	1	("20040040715").PN.	US-PGPUB; USPAT	OR	OFF	2006/04/05 10:25
L3	258	(tft (thin near5 transistor)) and ((crystal grain) near5 (boundary boundaries))	DERWENT	OR	ON	2006/04/05 11:08
L4	45	L3 and polysilicon	DERWENT	OR	ON	2006/04/05 11:08
L5	0	L4 and (OLED (organic near5 (EL electroluminescence electroluminescent light\$emissive light\$emitting light\$emission (light near3 (emissive emitting emission))))))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/04/05 11:08
S1	2	((("6177391") or ("6322625")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/04/04 14:11
S4	77424	(thin near3 transistor) or TFT	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 14:05
S16	492	((thin near3 transistor) or TFT) and (substrate with ((Polycrystalline adj silicon) polysilicon poly\$Si (silicon with crystal\$5))) and (substrate same (crystal\$5 with degree)))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 16:02
S17	76	S16 and (organic and (lumines\$5 luminophor\$3 lumino\$4 EL electroluminescence))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 14:11
S18	23	S17 and (crystal adj grain adj boundar\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 11:06
S19	1	("20020043662").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2005/04/29 15:38
S20	59	S16 and (crystal adj grain adj boundar\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 15:39
S21	12	S17 and ((crystal adj grain adj boundar\$4) with (degree angle orientation direction))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 15:40
S25	15	((thin near3 transistor) or TFT) and (substrate with ((Polycrystalline adj silicon) polysilicon poly\$Si (silicon with crystal\$5))) and (substrate same (crystal\$5 with degree))) and ((crystal adj grain adj boundar\$5) with (normal perpendicular))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 16:04

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S26	33	("4068020" "4755865" "4868014" "5142344" "5147826" "5242507" "5252507" "5266816" "5275851" "5278093" "5315132" "5318919" "5481121" "5485019" "5491107" "5531182").PN. OR ("5923997").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/29 16:20
S27	1	("20040085268").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2005/04/29 16:20
S28	1	("5923997").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2005/04/30 10:57
S29	492	(((thin near3 transistor) or TFT) and (substrate with ((Polycrystalline adj silicon) polysilicon poly\$Si (silicon with crystal\$5))) and (substrate same (crystal\$5 with degree)))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/04/05 10:14
S30	59	S29 and (crystal adj grain adj boundar\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 10:59
S31	2	S30 and (drive\$4 with (normal perpendicular))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 10:59
S32	3	("20030102508" "20030141503" "6177391").PN. OR ("6825494").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/30 11:02
S33	553	(((thin near3 transistor) or TFT) and (Polycrystalline adj silicon) polysilicon poly\$Si (silicon with crystal\$5)) and (drive\$4 with (normal perpendicular)))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 11:04
S34	156	S33 and (EL)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 11:04
S35	10	S33 and (crystal adj grain adj boundar\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 11:06
S36	162	(345/80).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/04/04 14:11
S37	20	S36 and boundary	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/04/04 14:11

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S38	20	S36 and boundaries	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/04/04 14:14
S39	61081	("313").CLAS.	US-PGPUB; USPAT	OR	OFF	2006/04/04 14:14
S40	258	(tft (thin near5 transistor)) and ((crystal grain) near5 (boundary boundaries))	DERWENT	OR	ON	2006/04/04 14:51
S41	45	S40 and polysilicon	DERWENT	OR	ON	2006/04/05 11:08
S42	6	((("6255146") or ("5759879") or ("5431126") or ("6444390") or ("20030013281") or ("20040253840"))).PN.	US-PGPUB; USPAT	OR	OFF	2006/04/04 14:29
S43	14	("4381202" "4933298" "5531182" "5549747" "5637515" "5639698").PN. OR ("5759879").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/04 14:49
S44	1	("20040085268").PN.	US-PGPUB; USPAT	OR	OFF	2006/04/04 14:51
S45	51	S39 and (tft (thin near5 transistor)) and ((crystal grain) near5 (boundary boundaries))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/04/04 14:52
S46	51	S39 and (tft (thin near5 transistor)) and ((crystal grain) near5 (boundary boundaries))	US-PGPUB; USPAT	OR	ON	2006/04/04 15:11
S47	1	("6177301").PN.	US-PGPUB; USPAT	OR	OFF	2006/04/04 15:41
S48	1	("5923997").PN.	US-PGPUB; USPAT	OR	OFF	2006/04/04 15:41